# NSN 5961-01-177-4718

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-177-4718

#### **Inclosure Material:**

Metal

**Overall Length:** 

1.218 inches

# **Mounting Facility Quantity:**

1

#### Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-111

#### **Mounting Method:**

Threaded stud

#### Features Provided:

Hermetically sealed case

#### **Overall Width Across Flats:**

0.437 inches

#### Thread Size:

0.190 inches

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

400.0 breakdown voltage, collector-to-base, emitter open and 350.0 breakdown voltage, collector-to-emitter, base open and 15.0 emitter to base voltage, static, collector open

#### **Current Rating Per Characteristic:**

5.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

47.0 watts small-signal input power, common-collector preset

#### Transfer Ratio:

30.0 static forward current transfer ratio, common-emitter

# Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

# **Special Features:**

Junction pattern arrangement: npn

## **Thread Series Designator:**

Unf

# Terminal Type And Quantity:

3 tab, solder lug and 1 wire hook

# Shelf Life:

N/a

# Unit Of Measure:

---

#### Demilitarization:

Yes - demil/mli

# **NSN 5961-01-177-4718** Transistor - Page 2 of 2

Fiig: A110a0

